Product data sheet

1. General description

NPN medium power transistor in an ultra thin SOT1061 leadless small Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package	Package	
	Nexperia	JEITA	
BC55PA	SOT1061	-	BC52PA
BC55-10PA			BC52-10PA
BC55-16PA			BC52-16PA

2. Features and benefits

- High current
- · Three current gain selections
- High power dissipation capability
- Exposed heatsink for excellent thermal and electrical conductivity
- Leadless very small SMD plastic package with medium power capability
- AEC-Q101 qualified

3. Applications

- Linear voltage regulators
- Power management
- Low-side switches
- MOSFET drivers
- · Battery-driven devices
- Amplifiers

4. Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base		-	-	60	V
I _C	collector current			-	-	1	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	2	А
h _{FE}	DC current gain						
	BC55PA	V _{CE} = 2 V; I _C = 150 mA T _{amb} = 25 °C	[1]	63	-	250	
	BC55-10PA		[1]	63	-	160	
	BC55-16PA		[1]	100	-	250	

[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$



60 V, 1 A NPN medium power transistors

5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	С
2	E	emitter		5
3	С	collector		B—
				Ė
			1 2	sym021
			Transparent top view	

6. Ordering information

Table 4. Ordering information

Type number	Package						
	Name	Description	Version				
BC55PA	HUSON3	plastic surface-mounted package; exposed	SOT1061				
BC55-10PA		die pad for good heat transfer; 3 leads					
BC55-16PA							

7. Marking

Table 5. Marking

Type number	Marking code
BC55PA	AW
BC55-10PA	ВН
BC55-16PA	ВЈ

60 V, 1 A NPN medium power transistors

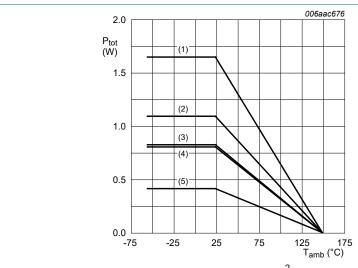
8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	60	V
V _{CEO}	collector-emitter voltage	open base		-	60	V
V _{EBO}	emitter-base voltage	open collector		-	5	V
I _C	collector current			-	1	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	2	Α
I _B	base current			-	0.3	Α
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms		-	0.3	Α
P _{tot} total power di	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	0.42	W
			[2]	-	0.83	W
			[3]	-	1.10	W
			[4]	-	0.81	W
			[5]	-	1.65	W
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm²
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 6 cm².
- [4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.
- [5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².



- (1) FR4 PCB, 4-layer copper, mounting pad for collector 1 cm²
- (2) FR4 PCB, single-sided copper, mounting pad for collector 6 cm²
- (3) FR4 PCB, single-sided copper, mounting pad for collector 1 cm²
- (4) FR4 PCB, 4-layer copper, standard footprint
- (5) FR4 PCB, single-sided copper, standard footprint

Fig. 1. Power derating curves SOT89

Product data sheet

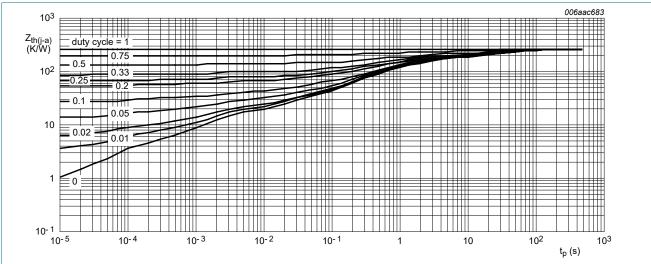
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9. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	298	K/W
			[2]	-	-	151	K/W
			[3]	-	-	114	K/W
			[4]	-	-	154	K/W
			[5]	-	-	76	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	20	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 1 cm².
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 6 cm².
- [4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.
- [5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².



FR4 PCB, single-sided, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

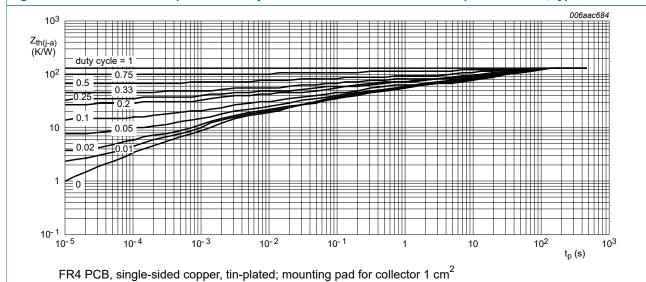
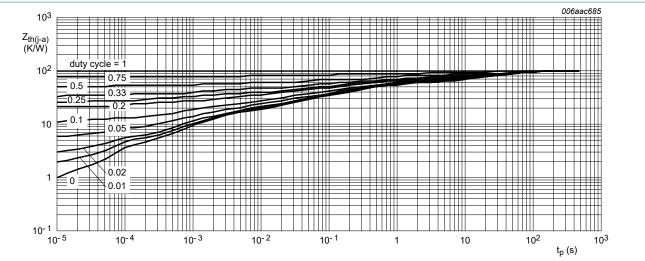


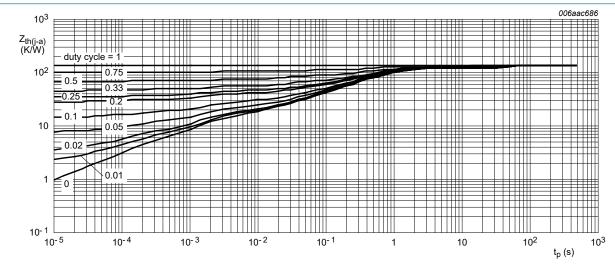
Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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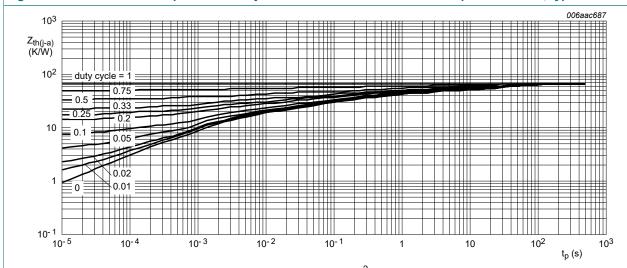
FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 6 cm²

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, 4-layer copper, standard footprint

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, 4-layer copper, mounting pad for collector 1 cm².

Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

Table 8. Characteristics

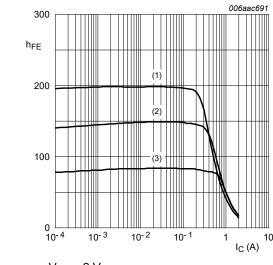
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = 100 \mu A; I_E = 0; T_{amb} = 25 °C$		60	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = 2 μA; I _B = 0 A; T _{amb} = 25 °C		60	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage	I _C = 0 A; I _E = 100 μA		5	-	-	V
I _{CBO}	collector-base	V _{CB} = 30 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
	cut-off current	V _{CB} = 30 V; I _E = 0 A; T _j = 150 °C		-	-	10	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	100	nA
h _{FE}	DC current gain						'
	BC55PA	V _{CE} = 2 V; I _C = 5 mA; T _{amb} = 25 °C	[1]	63	-	-	
		V _{CE} = 2 V; I _C = 150 mA; T _{amb} = 25 °C	[1]	63	-	250	
		V _{CE} = 2 V; I _C = 500 mA; T _{amb} = 25 °C	[1]	40	-	-	
	BC55-10PA	V _{CE} = 2 V; I _C = 5 mA; T _{amb} = 25 °C	[1]	63	-	-	
		V _{CE} = 2 V; I _C = 150 mA; T _{amb} = 25 °C	[1]	63	-	160	
		V _{CE} = 2 V; I _C = 500 mA; T _{amb} = 25 °C	[1]	40	-	-	
	BC55-16PA	V _{CE} = 2 V; I _C = 5 mA; T _{amb} = 25 °C	[1]	63	-	-	
		V _{CE} = 2 V; I _C = 150 mA; T _{amb} = 25 °C	[1]	100	-	250	
		V _{CE} = 2 V; I _C = 500 mA; T _{amb} = 25 °C	[1]	40	-	-	
h _{FE}	DC current gain	V _{CE} = 2 V; I _C = 5 mA; T _{amb} = 25 °C	[1]	63	-	-	
h _{FE}	DC current gain	V _{CE} = 2 V; I _C = 500 mA; T _{amb} = 25 °C	[1]	40	-	-	
V _{CEsat}	collector-emitter saturation voltage	I _C = 500 mA; I _B = 50 mA; T _{amb} = 25 °C	[1]	-	-	0.5	V
V _{BE}	base-emitter voltage	V _{CE} = 2 V; I _C = 500 mA; T _{amb} = 25 °C	[1]	-	-	1	V
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 \text{ °C}$		-	6	-	pF
f _T	transition frequency	V _{CE} = 5 V; I _C = 50 mA; f = 100 MHz; T _{amb} = 25 °C		100	180	-	MHz

^[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$

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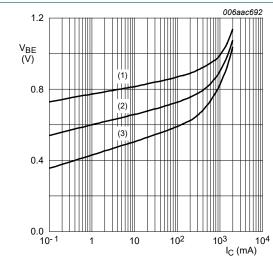
$$V_{CE} = 2 V$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55$$
 °C

Fig. 7. DC current gain as a function of collector current; typical values



$$V_{CE} = 2 V$$

(1)
$$T_{amb} = -55$$
 °C

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb}$$
 = 100 °C

Fig. 9. Base-emitter voltage as a function of collector current; typical values

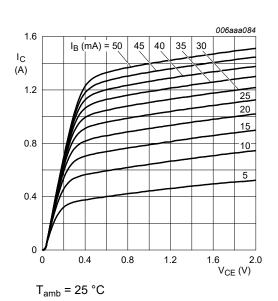
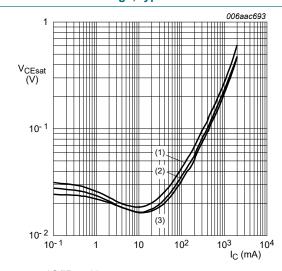


Fig. 8. Collector current as a function of collectoremitter voltage; typical values



(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 10. Collector-emitter saturation voltage as a function of collector current; typical values

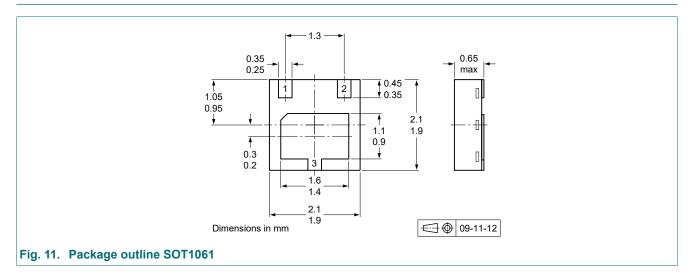
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11. Test information

11.1. Quality information

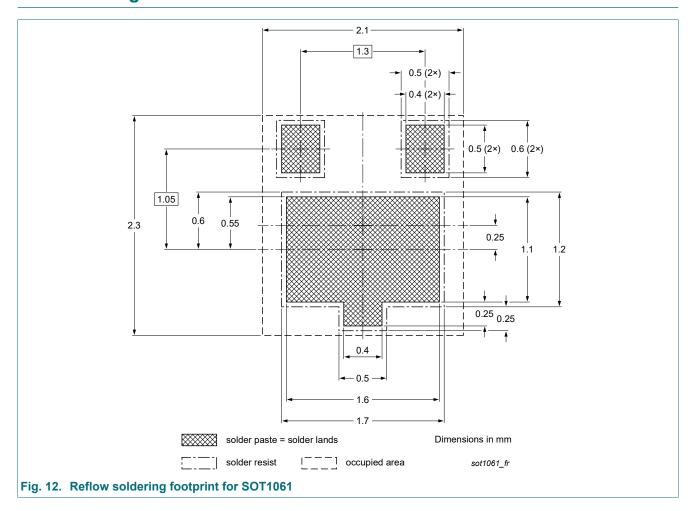
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



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14. Revision history

Table 9. Revision history

Table 9. Revision history					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
BC55PA_SER v.9	20220701	Product data sheet	-	BCP55_BCX55_BC55PA v.8	
Modifications:	 Series data sheet describing several packages reduced to series package. Package information removed. 				
BCP55_BCX55_BC55PA v.8	20111024	Product data sheet	-	BC637_BCP55_BCX55 v.7	
BC637_BCP55_BCX55 v.7	20070625	Product data sheet	-	BC637_BCP55_BCX55 v.6	
BC637_BCP55_BCX55 v.6	20050218	Product data sheet	CPCN200405029	BC635_637_639 v.4 BCP54_55_56 v.5 BCX54_55_56 v.4	
BC635_637_639 v.4	20011010	Product Specification	-	BC635_637_639 v.3	
BCP54_55_56 v.5	20030206	Product Specification	-	BCX54_55_56 v.4	
BCX54_55_56 v.4	20011010	Product Specification	-	BCX54_55_56 v.3	

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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